Secondary electron emission characteristics of oxide electrodes in flat electron emission lamp

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The present study concerns with the secondary electron emission coefficient, γ, of the cathode materials used in the newly developed flat electron emission lamp (FEEL) devices, which essentially integrates the concept of using cathode for fluorescent lamp and anode for cathode ray tube (CRT) to obtain uniform planar lighting. Three different cathode materials, namely fluorine-doped tin oxide (FTO), aluminum oxide coated FTO (Al₂O₃/FTO) and magnesium oxide coated FTO (MgO/FTO) were prepared to investigate how the variations of γ and working gases influence the performance of FEEL devices, especially in lowering the breakdown voltage and pressure of the working gases. The results indicate that the MgO/FTO bilayer cathode exhibited a relatively larger effective secondary electron emission coefficient, resulting in significant reduction of breakdown voltage to about 3kV and allowing the device to be operated at the lower pressure to generate the higher lighting efficiency. © 2016 Author(s). All article content, except where otherwise noted, is licensed under a Creative Commons Attribution (CC BY) license (http://creativecommons.org/licenses/by/4.0/).

I. INTRODUCTION

Owing to the increasing concerns of environmental sustainability globally, obtaining the mercury-free lighting has been one of the hotly pursued issues worldwide. To this respect, a recently developed flat electron emission lamp (FEEL) represents a potential technology capable of providing a mercury-free planar light source with high-uniformity.¹ The basic concept of FEEL is to utilize the energetic electrons emitted from the cathode to excite the cathodoluminescent phosphors coated on the anode and give rise to the desired luminance. However, unlike the traditional field emission configuration frequently used in display technologies,²-⁵ FEEL devices utilize the gas glow discharge to generate secondary electrons and hence can overcome the drawbacks of point-like radiations resulting from field emission schemes for a much more uniform planar lighting.⁶,⁷ Previous studies¹,⁶,⁷ indicated that, in order to obtain effective gas ionization and secondary electron emissions, FEEL devices were largely operated at the left hand side of the minimum of the Paschen curve, which describes the relation between the breakdown voltage for glow discharge and the parameter pd. Where p and d denote the working pressure of the discharged gas and the distance between the cathode and anode of the device, respectively. In general, the left hand-side of the Paschen curve represents an environment very sensitive to gas pressure with relatively higher breakdown voltage and kinetic energy and, hence, is relatively seldom explored in more commercialized lighting devices...
such as cold cathode fluorescent lamps (CCFLs),\textsuperscript{2} plasma display panel (PDPs),\textsuperscript{3} field emission displays (FEDs)\textsuperscript{4} as well as gas discharge lamps (GDLs)\textsuperscript{5} Therefore, in order to gain more insights on the unique physical properties associated with the harsh working environments and to improve the performance of FEEL devices, such as to lower the operation voltage and to enhance the luminance, more investigations are necessary. In particular, since the gas discharge prevailing in the present FEEL devices is mainly dominated by two factors, namely the operation pressure of the working gas and the cathode material used in the device. Therefore, how to obtain enough numbers and kinetic energy of the electrons with reduced operation voltage has become one of the critical issues for improving the lighting efficiency.

Previously, fluorine-doped tin oxide (FTO) had been used as the cathode electrode of the FEEL devices due to its transparent and conductive characteristics. Nevertheless, the requirement of relatively higher discharge voltage and shorter lifetime, presumably resulting from lower secondary electron emission coefficient ion-bombardment damage, have hindered the realization of the FEEL devices for practical use. Hence, developing protective layers capable of lowering the required discharge voltage and providing more robust endurance to ion-bombardment is necessary. It has been established that, in addition to the gas species and the operating pressure, the secondary electron yield of cathode is closely related to the discharge voltage.\textsuperscript{8–10} For instance, the breakdown voltage in PDP was found to reduce significantly if the ion-induced secondary electron emission of the cathode was increased.\textsuperscript{11,12} Thus, choosing materials with higher secondary electron emission coefficient should be beneficial to lower the discharge voltage and hence reduce the device power consumption. Moreover, previous studies had indicated that using MgO as the cathode of ac PDPs not only gave rise to advantages of low firing temperature and good durability,\textsuperscript{13,14} but also could serve as a stable protective layer overlying on the glass dielectric electrode.\textsuperscript{15,16} On the other hand, due to its high hardness, high abrasive resistance, good thermal and chemical stability, and high optical transparency Al\textsubscript{2}O\textsubscript{3} has become a choice of packaging material for electronics and optics industry.\textsuperscript{17,18} It is thus a potential cathode material for the present FEEL devices. In this study, we investigated the effects of cathode material on the luminescence of FEEL device by systematically comparing the influences of using three different cathode materials, namely FTO, MgO/FTO, Al\textsubscript{2}O\textsubscript{3}/FTO, on the device performances, while keeping the same phosphors-coated FTO as the anode. In particular, the effects on breakdown voltage and associated gas discharge characteristics will be addressed.

\section*{II. EXPERIMENTALS}

The FEEL devices investigated in this study were constructed with two FTO coated glasses separated by a 10mm spacing, as depicted schematically in Fig. 1. On the anode surface, a defined area of 30*30 mm\textsuperscript{2} was spin-coated with the P22-GN4 phosphors (Nichia, Ltd)/polyethylene oxide (PEO) slurry followed by a heat treatment at 450\degree C for 1 h. On the other hand, three different materials were used for the cathode electrodes, namely the pristine FTO-coated glass substrate, the bilayer Al\textsubscript{2}O\textsubscript{3}/FTO and MgO/FTO coated glass substrates. The MgO layers were deposited by RF-sputtering operating at a power of 2000 W with mixed gases of Ar + O\textsubscript{2}. A metallic Mg target was used and the flow rate of Ar and O\textsubscript{2} were 150 sccm and 4 sccm, respectively. The Al\textsubscript{2}O\textsubscript{3} layer was deposited by DC-sputtering using an Al metal target. The input power was 1500 W and the flow rate of Ar and O\textsubscript{2} were 150 sccm and 30 sccm, respectively. The thickness of both MgO and Al\textsubscript{2}O\textsubscript{3} was about 50 nm each. A glass tube was connected to the FEEL device and vacuum system for evacuating and adjusting nitrogen pressure in the space of the devices. The electrode and spacer were sealed by glass glue with infused 99.999%-pure nitrogen, argon, or neon as the working gas. The pressure of the working gases was monitored by a vacuum gauge attached to pumping system and was kept at a set constant value during the entire course of measurement. The pressure of the working gas inside the FEEL devices was varied between 0.04 torr and 40 torr by adjusting the gas flow rate.

The two electrodes of the FEEL device were connected to a DC voltage power supply (Keithley 248) and a picoammeter (Keithley 6485) to trigger the discharge and analyze the associated current-voltage characteristics and the Paschen curves. A 10 M\textOmega resistor was connected in series with FEEL device to limit and stabilize the discharge currents. The luminance meter, multi-function...
FIG. 1. The schematics of the FEEL device structure and the experimental setup for measuring the lighting and discharge properties.

color analyzer (Ruyico Tech.), was situated at the top of the transparent cathode for capturing the luminescence properties of the devices.

Kruithof\textsuperscript{19} pointed out that the values of secondary electron emission coefficient can be very sensitive to the surface conditions of the electrodes. Therefore, in all experiments plasma pre-treatment was carried to clean the electrode surface prior to discharge measurements. The pre-treatment was carried out by nitrogen plasma at 0.15 torr with an operating voltage of 3kV for 10 min.

III. RESULTS AND DISCUSSIONS

Figure 2 shows the current-voltage characteristics (IVCs) of FEEL devices with the three different cathode materials, namely FTO, MgO/FTO and Al\textsubscript{2}O\textsubscript{3}/FTO. It is noted that, except for the cathode material, all the conditions for the FEEL devices were the same and the pressure of the operating gas (nitrogen in this case) was kept at a certain constant value (e.g. 0.11 torr) during the entire course of measurement. In general, a typical IVC of the discharge type device would contain the common features corresponding to the following physical processes, namely background ionization, electron multiplication leading to the breakdown voltage of the Townsend discharge, voltage drop, the normal discharge, the abnormal discharge.\textsuperscript{20,21} Starting from the regime of background ionization, the current is arisen from ionization of gas molecules induced by ultraviolet, cosmic radiation and radioactivity, thus the initial current is very small (\(\sim 10^{-9}\)A). As the electric field is increased, although the number of ions and electrons are both increased, the increased effective recombination coefficient also promotes the neutralization between the two. Therefore, the total number of charged particles does not increase significantly in this regime and the current remains relatively small. With further increase in applied voltage, the multiplication process becomes more and more frequent and the electron emission from the cathode starts to engage. In this stage, in addition to an avalanche-like increase in current (from nA to \(\mu\)A), Crowe\textsuperscript{22} pointed out that the slope of the IVC also appears to be negative at the breakdown. It is apparent from Fig. 2 that the breakdown voltage (\(V_b\)) is very much dependent on the cathode material used. Namely \(V_b\) for FTO, Al\textsubscript{2}O\textsubscript{3}/FTO, and MgO/FTO cathodes are 4330V, 1520V, and 920V, respectively.

The apparent negative resistance appearing immediately after breakdown is a classical characteristic of dc gas discharge. The electrons giving rise to the avalanche-like current increase are mainly from two sources: gas ionization described by the Townsend’s first ionization coefficient and electrons emitted from cathode material due to the bombardment of energetic ions represented
by the secondary electron emission coefficient, $\gamma$. Both $\alpha$ and $\gamma$ are playing decisive roles for determining the breakdown voltage of gas discharge through the Paschen expression:\textsuperscript{20,23,24}

$$V_b = \frac{Cpd}{\ln[Apd/\ln(1+1/\gamma)]}.$$  \hspace{1cm} (1)

Where $A$ and $C$ represent the phenomenological constants closely related to the Townsend’s first ionization coefficient $\alpha$, $\gamma$ represents the secondary electron emission coefficient of cathode, $p$ is the gas pressure inside the discharge space, and $d$ is the distance between the two electrodes. Thus, by analyzing the relation between $V_b$ and $pd$, also known as the Paschen curve, one can investigate how the gas species and cathode materials affect the performance of the device in a more quantitative manner.

Figure 3 shows the Paschen curves for FEEL devices operating with the same gas but different cathode materials (Fig. 3(a)) and that operating with different gases but with the same cathode material (Fig. 3(b)). In order to obtain a more comprehensive picture, the gas pressure has been covered nearly three orders of magnitude ($pd = 0.10-40$ torr$\cdot$cm). It is apparent that $V_b$ is much more sensitive to the cathode material on the left hand side of the Paschen curve minimum, suggesting

FIG. 2. The current-voltage characteristics of FEEL devices at the operation of 0.11 torr nitrogen for FTO, Al$_2$O$_3$/FTO, and MgO/FTO thin film as the cathode electrodes.

FIG. 3. (a) Breakdown voltages measurement at three different cathode materials (FTO, Al$_2$O$_3$/FTO, and MgO/FTO). Each cathode material is compared at the same pressure $\times$ distance product. (b) Breakdown voltages measurement at three different working gases (nitrogen, argon, and neon). Each working gas is compared at the same pressure$\times$distance product.
that, at lower gas pressures, the electron emission from the cathode may become the dominant process for the glow discharge behavior. In particular, the incorporation of a 50 nm-thick oxide layer on the cathode appears to have significantly lowered the breakdown voltage with MgO being more effective than Al₂O₃. It is also interesting to observe that beyond the Paschen curve minimum toward the higher \( pd \) values \( V_b \) behaves essentially the same for all three different cathodes, indicating that the electron emission from the cathode is less influential to glow discharge prevailing in this regime. On the other hand, with different working gases, namely \( \text{N}_2 \), Ar, and Ne, the breakdown behavior becomes more sensitive to the gas species in the higher \( pd \) regime (Fig. 3(b)). As can be seen from Fig. 3(b), the slope of the Paschen curves on the right hand side of the minimum appears to be much smaller than that on the low \( pd \) regime. In particular, for Ar and Ne gases, the breakdown voltage remains at a relatively low value over a wide range of pressures, presumably due to the differences in the first ionization coefficient \( (\alpha) \). Indeed, as indicated by Roth, the phenomenological constants \( A \) and \( C \) in the expression representing the Townsend first ionization coefficient for \( \text{N}_2 \), Ar, and Ne gases are 1060 ion-pairs/m-torr and 34200 V/m-torr, 1200 ion-pairs/m-torr and 20000 V/m-torr, and 400 ion-pairs/m-torr and 10000 V/m-torr, respectively.

In order to obtain a more quantitative measure of the secondary electron emission coefficients for the cathodes used in this study, the data shown in Fig. 3(a) were analyzed by using expression (1). By differentiating the Paschen’s expression with respect to \( pd \), the slope of Paschen curve at certain \( pd \) value is given by:

\[
\frac{d(V_b)}{d(pd)} = \frac{c[\ln(\frac{Apd}{\ln(1+1/\gamma)}) - 1]}{[\ln(\frac{Apd}{\ln(1+1/\gamma)})]^2}.
\]

Right at the minimum of the Paschen curve, where the derivative of expression (2) should be zero and following relations can be obtained:

\[
\ln\left(\frac{A(pd)_{\text{min}}}{\ln(1+1/\gamma)}\right) = 1.
\]

and

\[
(pd)_{\text{min.}} = \frac{e}{A} \ln(1 + \frac{1}{\gamma}).
\]

By plugging in \((pd)_{\text{min}} \approx 1.1\) torr-cm for all three cases, the obtained \( \gamma \) values for FTO, Al₂O₃/FTO, and MgO/FTO cathodes are 0.0067, 0.0088, and 0.0114, respectively. It has been show that electron yield, both by ion- and photo-induced processes is strongly influenced by the band gap and electron affinity of the material. While the former is important to breakdown voltage, the latter is more relevant to the secondary electron emission. The materials that have lower electron affinities are potentially having a higher electron emission yield. The electron affinity for MgO and Al₂O₃ are 0.8 eV and 1.0 eV, respectively. It is apparent that our results are consistent with this general trend. These values, although can explain the tendency of reducing the breakdown voltage by the incorporation of the Al₂O₃ and MgO layers on the surface of the cathode, nevertheless, are somewhat too small to account for substantial reduction of breakdown voltage in the low pressure regime. In particular, comparing to the values of 0.040–0.099 reported for MgO by focused ion beam system with Ne⁺ ions of \( \sim 10^{10} \) ions/cm\(^3\), the values are about a factor of 4–10 smaller. The differences may have resulted from the measuring conditions used and/or the ion species that were used to induce the secondary electrons. Moreover, the values were obtained based on one single condition and, thus, may not reflect the actual situations over the entire range of operating pressures.

Alternatively, one can also use expression (1) to calculate the coefficient \( \gamma \) at every operation condition directly. Figure 4 displays the results for a total of 15 FEEL devices operated with nitrogen gas of various pressures. Apparently, the value of \( \gamma \) is indeed very much dependent on the parameter \( E/p \), where \( E \) and \( p \) are the effective field and pressure inside the glow discharge space, respectively. It is also interesting to observe that for each set of samples the data are more or less falling into the same curve, indicating that the characteristics are genuine and are reflecting the response of cathode to the incoming ions. We note that in the calculation the values of constants
A and C being used are 1060 ion-pairs/m-torr and 34200 V/m-torr, respectively. These values are valid only when the parameter $E/p$ is within the range of $C/2 < E/p < 3C$, as indicated by the shaded area shown in Fig. 4. Nevertheless, the results, at least for MgO, are in much better agreement with the abovementioned values obtained from focus ion beam measurements. It is also worth mentioning that the results displayed on the lower $E/p$ values (i.e. left to the minimum) are almost the same for all three different cathode materials, which apparently is not reflecting the real situations, because it is in the gas ionization dominant regime.

Next we will discuss how the “effective” $γ$ values affect the performance of the FEEL devices. Previously, it has been demonstrated that in order to obtain adequate electron kinetic energy to
excite the phosphors on the anode, the FEEL devices were most operating in the $pd$ range of 0.09-0.2 torr-cm with a typical operation voltage of $\sim 1000$ V.\textsuperscript{1,6,7} Figure 5 shows the luminance as a function of operating gas pressure for FEEL devices with the three different cathode materials in the pressure range of 0.04-0.25 torr. Significant lighting luminance enhancement from $\sim 880$ cd/m\textsuperscript{2} for FEEL with the FTO cathode to over $\sim 2000$ cd/m\textsuperscript{2} for that with MgO/FTO is evident. The efficiency as a function of pressure is also displayed in the inset of Fig. 5 for comparison. The lighting efficiency is around 10-11 Lm/W for device with FTO as cathode electrode, which can be enhanced up to 23-27 Lm/W by coating a layer of MgO on FTO. Based on Fig. 4, the $\gamma$ values at $E/p \sim 10000$ V/torr-cm for FTO, Al\textsubscript{2}O\textsubscript{3}/FTO, and MgO/FTO are 0.193, 0.263, and 0.396, respectively. It is apparent that the larger $\gamma$ values can effectively reduce both the working gas pressure, which in turn reduces the collisions between the electrons and gas ions and preserves the kinetic energy of electrons necessitated for exciting phosphors at the anode. It is also noted that FEEL devices with both MgO/FTO and Al\textsubscript{2}O\textsubscript{3}/FTO as cathode materials exhibited an enhancement in device lifetime by about 4 times, presumably due to the reduction of breakdown voltages.

IV. CONCLUSIONS

In conclusion, by systematically analyzing the current-voltage characteristics and associated Paschen curves of a series of flat electron emission lamp (FEEL) devices with three different cathode materials (MgO/FTO, Al\textsubscript{2}O\textsubscript{3}/FTO, FTO), an experimental method for determining the secondary electron emission coefficient ($\gamma$) as a function of reduced electric filed was demonstrated. It is observed that, while using the Paschen curve minimum to calculate $\gamma$ is more convenient, the values obtained were about an order of magnitude smaller than those reported by using standard focus ion beam measurement systems. On the other hand, by calculating the each point of the Paschen curve gave a much better account for the effective $\gamma$ values for real operation conditions. Our results show that, under the typical operation conditions of FEEL devices, the $\gamma$ values for FTO, Al\textsubscript{2}O\textsubscript{3}/FTO, and MgO/FTO are 0.193, 0.263, and 0.396, respectively. The larger $\gamma$ value obtained for MgO consistently accounts for both the significant reduction in breakdown voltage and marked enhancement in lighting efficacy and device lifetime.

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